

25 OCT 2019

Effect of PROCESS variation, Temp & Voltage vari<sup>n</sup>. on filter response.

Absolute Value of  $R \pm 20\%$ .

of  $C \pm 15\%$ .

$G_m \pm 40\%$ .

Filter Corner freq  $\pm 50\%$  easily over PVT

However, by using layout matching techniques.

$R$  mismatch  $0.1\%$ ; Cap mismatch  $0.1\%$

$G_m$  mismatches  $< 0.5\%$ . Can be achieved.

→ Filter Shape is preserved. — Corner freq  $\propto \frac{1}{RC}$  changes over PVT.

Filter Tuning over PVT. → make sure  $\frac{1}{RC}$  or  $\frac{g_m}{C}$  is trimmed to get desired  $f_{\text{corner}}$ .

1. Digital programming
2. Automatic Tuning on-chip.

Master Slave.

Haidich  
Khorramabadi  
Paper

①. Use phase difference @ o/p of filter & compare to crystal clock. reference

K.S. Tan  
paper

② Create VCO using integrators & then compare oscillation freq. to Reference.

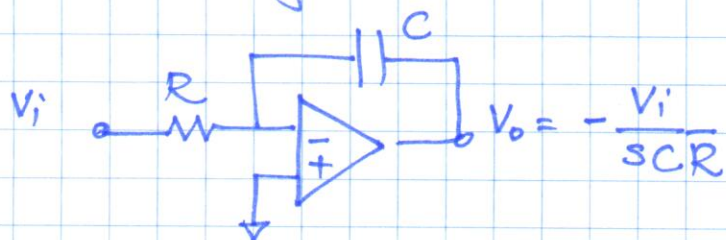
③ DSP based filter calibration  
— used in most radios we use today.



## Switched-Capacitor Circuits - Introduction

### Motivation:

RC integrator used in CT filters



$$V_o = -\frac{V_i}{sCR}$$

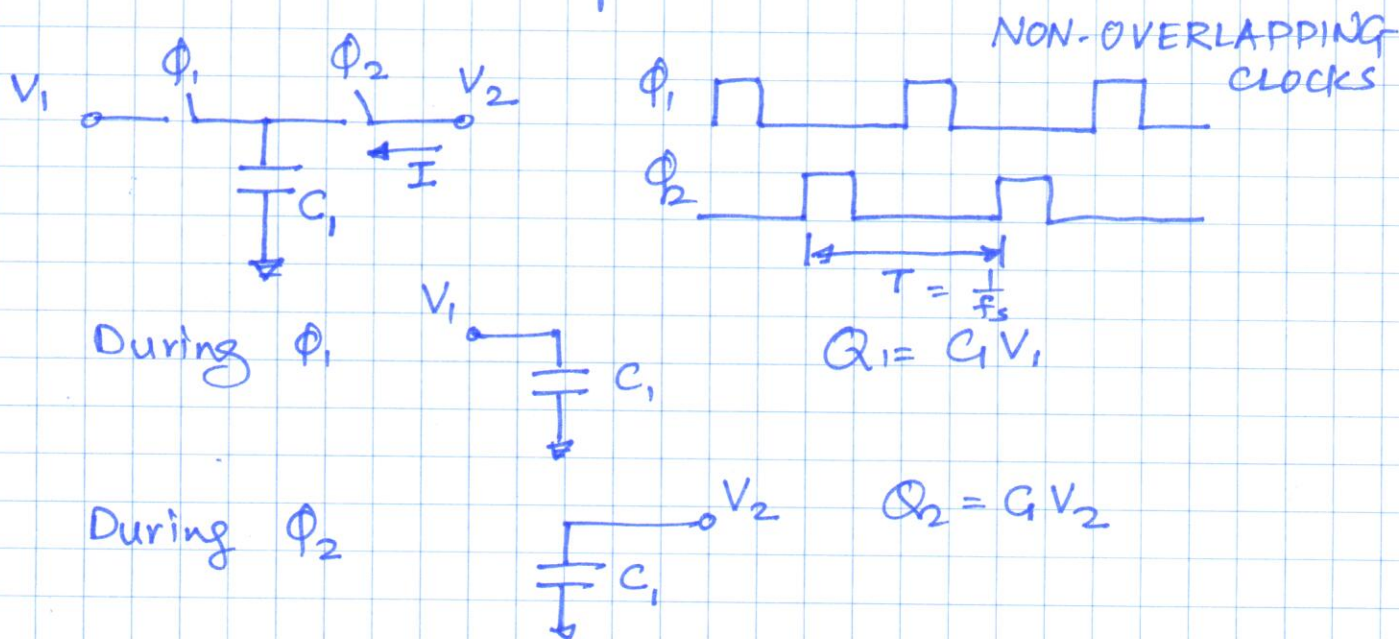
$$R \rightarrow \pm 20\%$$

$$C \rightarrow \pm 10-15\%$$

$$RC \rightarrow \pm 35\% \text{ variations}$$

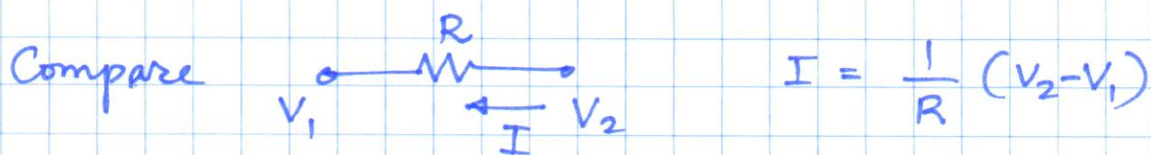
CT Filter designed using various methods discussed in Lecture 22 will result in  $f_{3dB}$  (corner frequency) variation upto  $\pm 50\%$ .  $\rightarrow$  Require Tuning etc.

Consider switched-capacitor circuit below:



Current flowing from  $V_2$  to  $V_1$  =  $\frac{\Delta Q}{\Delta t}$

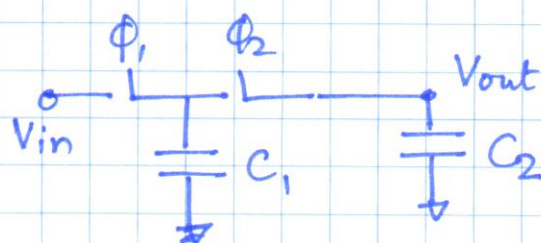
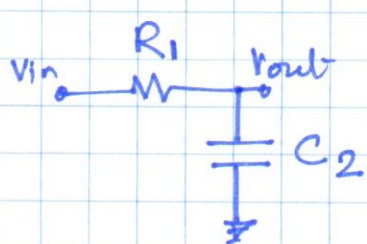
$$I = \frac{\Delta Q}{T} = \frac{C_1 (V_2 - V_1)}{T} = f_s C_1 (V_2 - V_1)$$



Equivalent resistor  $R = \frac{T}{C_1} = \frac{1}{f_s C_1}$

2 → Switched-Capacitor Resistor Implementation.

FIRST ORDER Low Pass filter



$$\omega_p = \frac{1}{R_1 C_2} = \frac{f_s C_1}{C_2} = f_s \left( \frac{C_1}{C_2} \right)$$

Sampling Clock  
generally derived from  
Crystal Reference  
~5 ppm accuracy

Capacitor ratios  
Proper layout Techniq.  
0.1% matching possible.

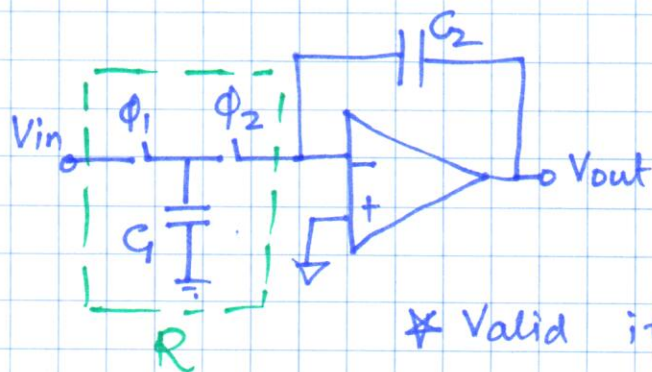
Very accurate frequency Response over PVT.

Ref:

Analog Sample-Data Filters - David. Fried,  
JSSC - Aug 1972.



## Switched-Cap. Integrator



$$\frac{V_{out}}{V_i} \approx -\frac{1}{sRC_2} = -\frac{f_s \left(\frac{C_1}{C_2}\right)}{s}$$

\* Valid if  $f_s \gg$  frequency of interest  
example UGF of Integ.

Rule of Thumb at least factor of 10

Lets get into details

Exact Analysis

Continuous-Time

Z-domain Refresher

Start from differential equation  $x(t)$   
eg:  $\dot{y}(t) = x(t) - y(t)$

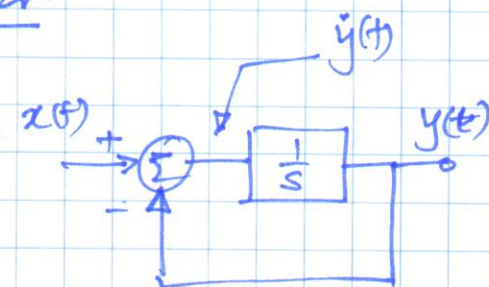
Laplace Transform

$$sY(s) = X(s) - Y(s)$$

$$H(s) = \frac{Y(s)}{X(s)} = \frac{1}{s+1}$$

$$s = j\omega$$

$$H(j\omega) = \frac{1}{j\omega + 1}$$



plot  $|H(j\omega)|$   
phase  $H(j\omega)$

Discrete-Time Analysis  $\rightarrow$  assumption Nyquist sampling criteria

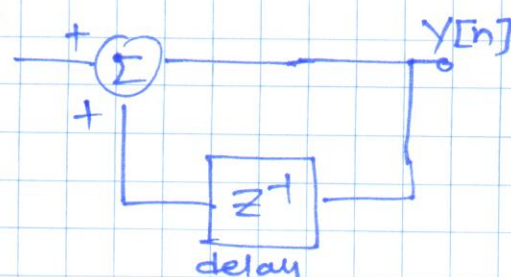
Processing signal at discrete-timepoints

Start from difference equations

eg:

$$y[n] = x[n] + y[n-1]$$

Delay operator  $z^{-1}$



$$Y(z) = X(z) + z^{-1} Y(z)$$

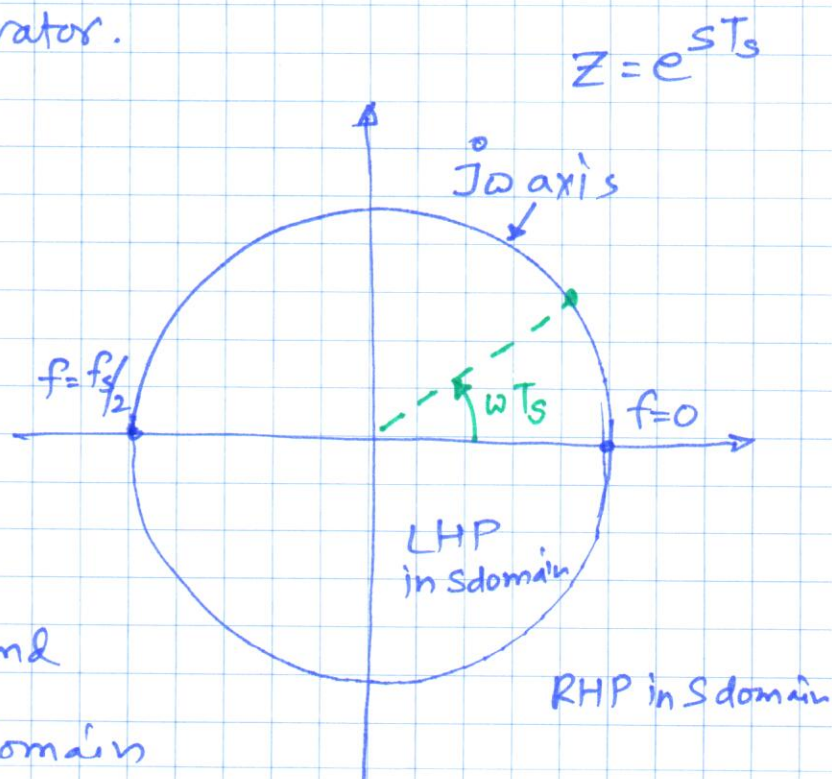
$$H(z) = \frac{Y(z)}{X(z)} = \frac{1}{1 - z^{-1}}$$

$$z = e^{sT} = e^{j\omega T} = \cos(\omega T_s) + j\sin(\omega T_s)$$

→ plot  $H(z)$  is mag & phase response.

Z-transform operator.

$$\begin{aligned} nT_s &\rightarrow 1 \\ (n-1)T_s &\rightarrow z^{-1} \\ (n-\frac{1}{2})T_s &\rightarrow z^{-1/2} \\ (n+1)T_s &\rightarrow z^{+1} \end{aligned}$$



$s = j\omega$  axis is  
warped/wrapped around  
unit circle in  $z$  domain

$$\begin{aligned} f=0 & \quad z=1 \\ f=f_s/2 & \quad z=-1 \end{aligned}$$

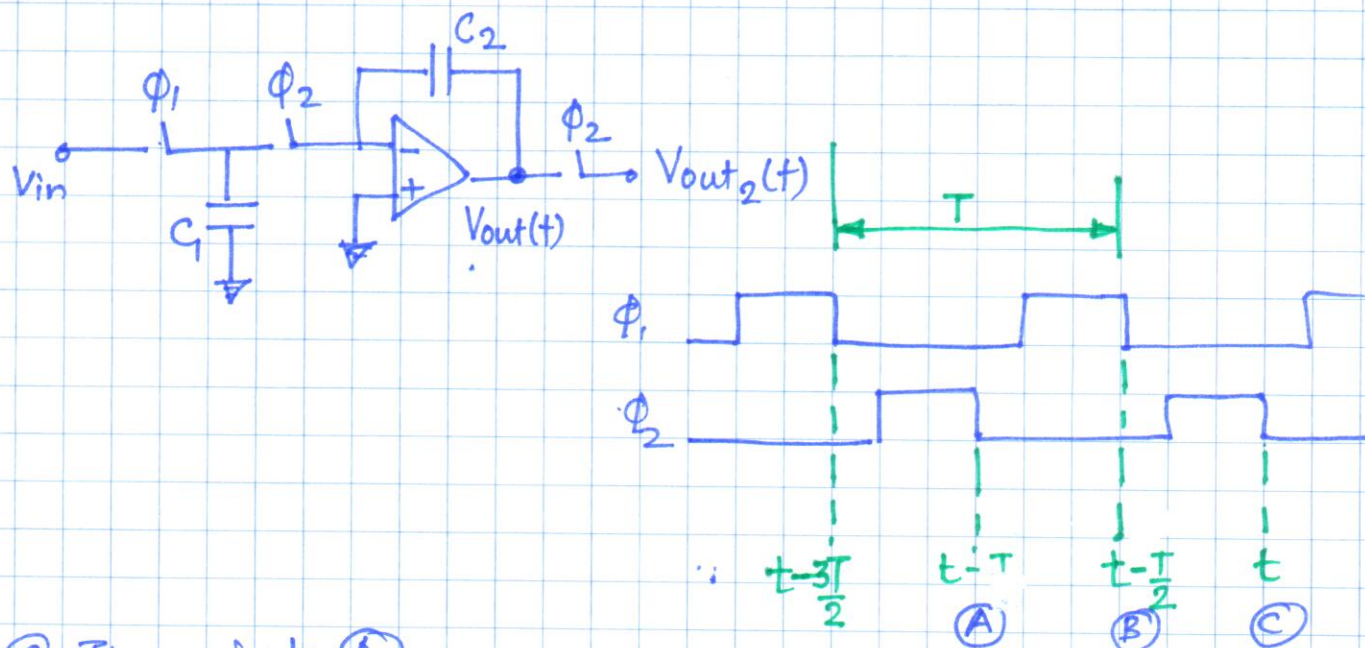
After  $f = f_s/2$ , frequency response repeats.

→ Note  $s$ -domain integrator → pole @ DC  
 $z$ -domain → pole @  $z=1$

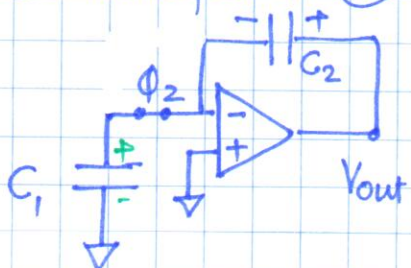


## BACK TO SWITCHED-CAP CIRCUITS

Key concept : Charge Conservation



@ Time point (A)

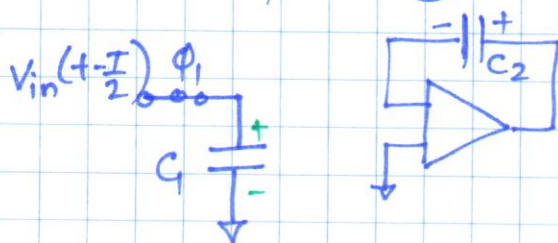


No charge on  $C_1$  (both sides @ ac virtual ground)  
 $Q_{C_1+} = 0$

Charge on -ve plate of  $C_2$

$$Q_{C_2-} = -C_2 V_{out}(t-T)$$

@ Timepoint (B)



Charge on +ve plate of  $C_1$

$$Q_{C_1+} = C_1 V_{in}(t - \frac{T}{2})$$

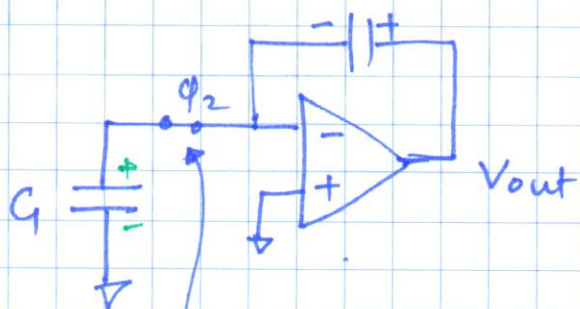
Charge on -ve plate of  $C_2$

$$Q_{C_2-} = -C_2 V_{out}(t-T)$$

@ Timepoint (C) — charge redistribution happens.

$$Q_{C1+} = 0$$

$$Q_{C2-} = -C_2 V_{out}(t)$$



No path for charge to escape

→ opamp - zero i/p current  
-ve feedback makes sure  
-ve i/p is driven to virtual gnd.

Charge Conserved from (B) to (C)

$$\overbrace{Q_{C1+} + Q_{C2-}}^{(B)} = \overbrace{Q_{C1+} + Q_{C2-}}^{(C)}$$

$$C_1 V_{in}(t - \frac{T}{2}) - C_2 V_{out}(t - T) = 0 - C_2 V_{out}(t)$$

$$V_{out}(t) = V_{out}(t - T) - \frac{C_1}{C_2} V_{in}(t - \frac{T}{2})$$

If we sample o/p during  $\phi_2$ , then

$$V_{out_2}(t) = V_{out_2}(t - T) - \frac{C_1}{C_2} V_{in}(t - \frac{T}{2})$$

Z-transform

$$V_{out_2}(z) = z^{-1} V_{out_2}(z) - \frac{C_1}{C_2} V_{in}(z) \cdot z^{-1/2}$$

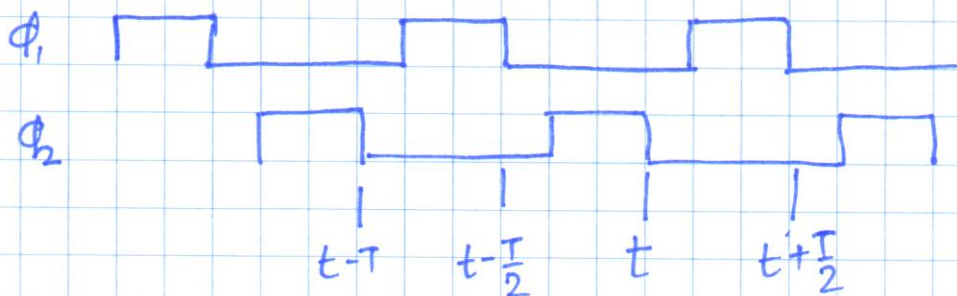
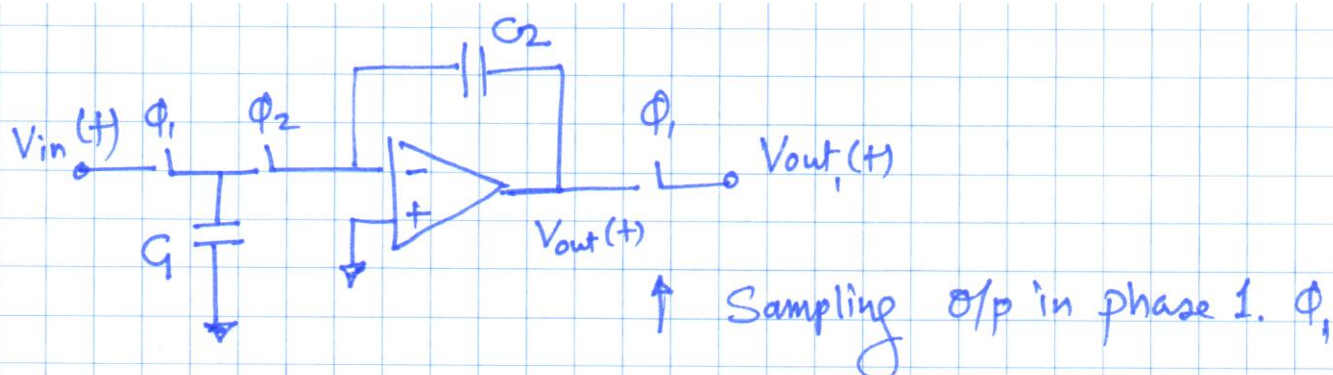
$$V_{out_2}(z) = \frac{-\left(\frac{C_1}{C_2}\right) z^{-1/2}}{1 - z^{-1}} V_{in}(z)$$

half delay from  $V_{in}$  to  $V_{out}$

inverting confis

pole @  $z=1 \Rightarrow$  Sdomain pole @ DC integrator  $\frac{1}{s}$





During  $\phi_2$   $V_{out}(t)$  changes. — Then we observe <sup>(Sample)</sup> o/p in  $\phi_1$  ( $\frac{T}{2}$  later).  $\rightarrow z^{-1/2}$  delay later

$$V_{out_1}(t + \frac{T}{2}) = V_{out_2}(t)$$

$$z^{+1/2} V_{out_1}(z) = V_{out_2}(z)$$

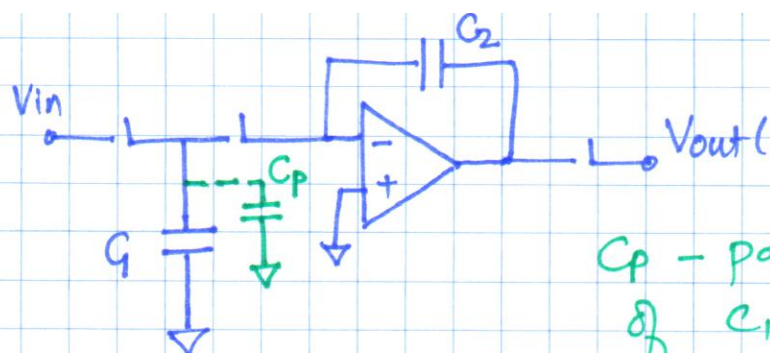
$$V_{out_1}(z) = z^{-1/2} V_{out_2}(z)$$

$$V_{out_1}(z) = \frac{-\left(\frac{C_1}{C_2}\right) z^{-1}}{1 - z^{-1}} V_{in}(z)$$

Full delay

Transfer Function depends on when you sample the o/p. — Time Variant Discrete Time circuits





$C_p$  - parasitic @ top plate node  
 of  $C_1 \rightarrow$  due to routing  
 $\rightarrow$  switches  
 $\rightarrow$  parasitics of  $C_1$   
 $\rightarrow$  can't be avoided.

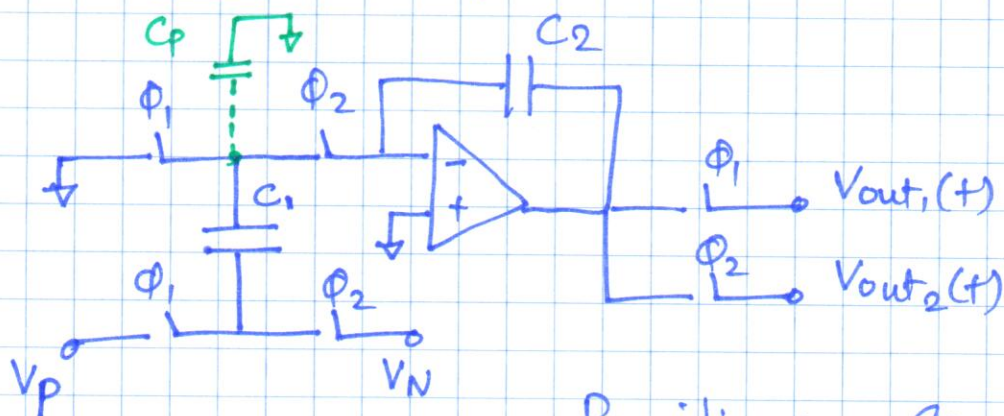
All other parasitics - don't affect integration operation.

Impact of parasitics

$$V_{out}(z) = - \frac{\left( \frac{C_1 + C_p}{C_2} \right) z^{-1}}{1 - z^{-1}} V_{in}(z)$$

Advantage of  $\left( \frac{C_1}{C_2} \right) \Rightarrow 0.1\%$  matching accuracy is lost.  
 $C_p$  can be as high as 10% of  $C_1$ .  
 Also, will not match.

$\rightarrow$  Innovation . Parasitic Insensitive SC Integrator



Parasitic cap  $C_p$ , always @  
 virtual gnd node.

$\rightarrow$  Doesn't contribute to charge  
 conservation process.